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April 1st, 2010 Renesas Electronics Corporation

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M61112FP

Coil-less VIF/SIF

REJ03F0022-0100Z Rev.1.0 Sep.16.2003

Description

M61112FP is a semiconductor integrated circuit consisting of IF signal processing for NTSC system. The circuit includes VIF amplifier, Video detector, Coil-less VCO, APC detector, IF/RF AGC, SIF limiter and FM detector functions, which permits a smaller tuner system.

Feature

- Inter and split system for NTSC
- Built-in coil-less VCO
- Non alignment AFT
- 3.58MHz/4.0MHz Reference frequency
- Built-in mute function VIF and SIF
- Built-in SIF buffer
- · Receive FM radio

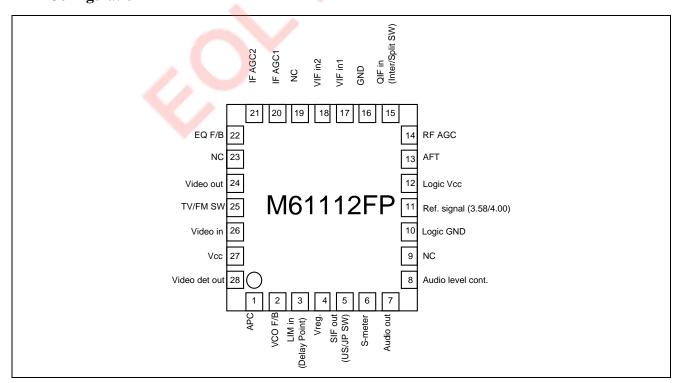
Application

TV set, VCR tuners.

Recommended Operating Condition

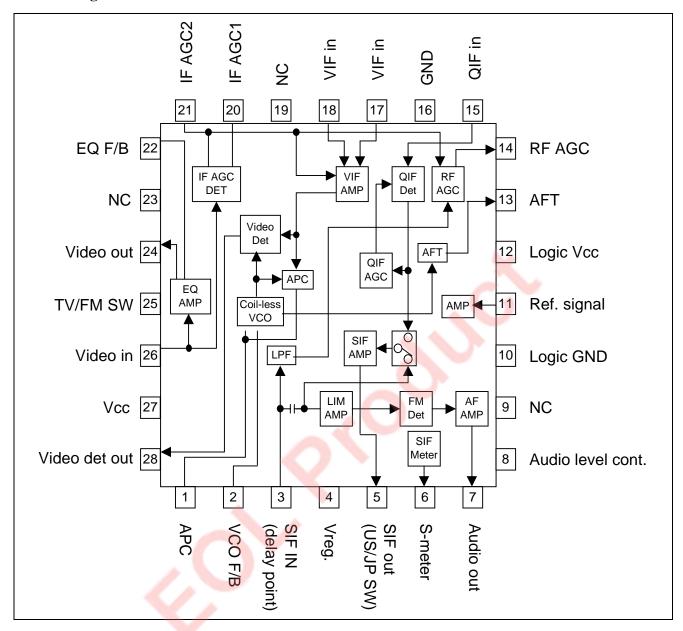
Operating power supply voltage 5+/-0.25V

Pin Configulation





Block Diagram



Pin Description

Pin	Pin		Terminal	
No.	Name APC	Function APC filter terminal.	Voltage 2.6V	Equivalent Circuit
			(no input)	3.4V 21K 300 W 1
				1.5K\$ 200uA
2	VCO F/B	VCO Feedback terminal. The feedback control is to keep the internal VCO of the uniform free-running frequency. This terminal has dual function,	3.0V	27 To mute SW 20K ₹10K
		connecting to gnd select mode with VIF/SIF defeat.		
3	SIF in (Delay Point)	RF AGC Delay terminal.4.5MHz SIF signal "LIM IN" is input at this pin which has dual function. The RF AGC Delay Point is set up of DC component of this	2.1V	27 ————————————————————————————————————
		signal. AC component is FM signal.	Κ,	3 40 5.1K 20K 20K 20K 20K 17.5K 17.5K 17.7K
4	Vreg	Regulated voltage output terminal. The voltage is approximately 3 V.	3.0V	27 50 \$ \$
				9.9K \$ 6.2K \$ \$
5	SIF out (US/JP SW)	SIF output terminal. FM signal which is converted to 4.5MHz is output. This pin has dual function of being VIF VCO type selection terminal.	2.2V	27 30K 30K
		Connect to GND with 1.5kΩ; JPN"58.75MHz" No connect; USA"45.75MHz"		5 12mA 6p 1

Pin No.	Pin Name	Function	Terminal Voltage	Equivalent Circuit
6	S-meter	S-meter terminal. This Pin changes DC Voltage to keep regular the output amplitude of Pin5.It Does the AGC function. However, The output of this Pin is about 0V when it become out of AGC range for small input.	2.2V 0V	6 100 mm m
7	Audio out	Sound output terminal. De-emphasis is achieved by external components.	2.3V	27 200\$ 0 7 7 7 7 7 7 7 7 7 7 7 7 7
8	Audio Level Cont.	AF Bypass terminal. It is connected to one of the input of a differential amplifier, external capacitor provides AC filtering. When resistor is connected in series with capacitor, it is possible to lower the amplitude of the audio output. When audio output terminal is not use, please connect this terminal to GND.	2.8V	27 8 30K 1K 30K 1K 30K 1K 30K 1K
9	NC Logic	Ground terminal for Logic and	— GND	
	GND	Ref amp.		(10)
11	Ref Signal (3.58/ 4.00)	Reference signal input terminal. It is input external signal with sinewave. In case of 4MHz mode, connect to GND with 4.7 k Ω .	3.2V	11) 4.0V 4K 4K 4.5K 8p 2p 9
12	Logic Vcc	Power supply terminal for Logic and Ref amp.	5V	(12)

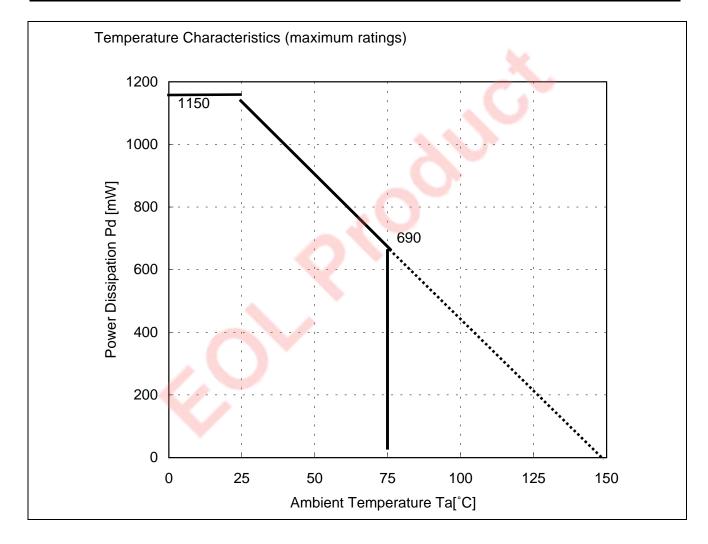
Pin No.	Pin Name	Function	Terminal Voltage	Equivalent Circuit
13	AFT (FM Carrier det)	AFT output terminal. Because of pulse-like signal output, Smoothing capacitor is connected externally with TV mode. Under FM mode,this pin is carrier detector. Active ; High Non-active ; Low	5V 0V	350K 350K 350K 350K
14	RF AGC	RF AGC output terminal. It is current drive type.	5V 0V	27 \$\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\
15	QIF in (Inter/ Split SW)	QIF Input terminal with SPLIT. This pin has dual function, The other is INTER/SPLIT SW. INTER: GND SPLIT: DC Open	2.4V	32V To INTER/ SPLIT SW 1.5K W 1.5K W 1.5K
16	GND	Ground terminal for VIF and SIF.	GND	16
17	VIF in1	IF signal after SAW filter is input. It is a balance-type input.	1.5V	27 2.3V 2K
18	VIF in2	-	1.5V	17
19	NC	_	_	_

Pin No.	Pin Name	Function	Terminal Voltage	Equivalent Circuit
20	IF AGC 1	IF AGC filter terminal 1. External capacitor effects AGC speed. When this terminal is grounded,the effect of VIF amp, becomes minimum gain.	4.9V 2.2V (TV)	27 10K 50 W W W
21	IF AGC 2	IF AGC filter terminal 2.	4.0V 2.0V (FM)	20
22	EQ AMP F/B	Equalizer feedback terminal. It is possible to change the AC response of the video signal by attaching L,C,R to this terminal.	2.3V	22 K 22
23	NC	_	(-
24	Video out	Video out terminal.	2.3V (no input)	27 200\$ 9 24 1.4mA
25	TV/FM SW	TV/FM SW terminal. Open: TV Mode GND: FM Mode Connecting to GND with $100k\Omega$ or adding to $1/2$ Vcc at this terminal select to search mode.	5V (TV)	27 100K 100K 25 W 100M 100M 100M 100M 100M 100M 100M 10

Pin No.	Pin Name	Function	Terminal Voltage	Equivalent Circuit
26	Video in	This terminal is input the video signal from Pin5"Video det out" by SIF trap. Input this terminal to DC of Video det signal is necessary for IF AGC function.	=PIN28	27 100 100 100 100 100 100 100 100 100 10
27	Vcc	Power supply terminal for VIF and SIF.	5V	<u> </u>
28	Video det out	Video detector output terminal. SIF trap and SIF BPF are connected to this terminal. It is necessary connecting external resistor for drive, because open emitter configuration.	2.3V (Load of 240Ω/ no signal)	27 50 \$ 0

Absolute maximum ratings (Ta=25°C, unless otherwise noted)

Parameter	Symbol	Ratings	Unit	Note
Supply Voltage	Vcc	6.0	V	_
Total Power Dissipation	Pd	1150	mW	Conditions of this ratings. (1) 70x70mm² 1.6mmt (1 layer board) (2) Board material = Glass epoxy (FR-4) (3) Cupper share of board = 50% (4) Wind velocity = 0m/sec It changes with the material of mounting board, the
				Cupper share, etc.
Operating Temperature	Topr	-20 to 75	°C	_
Storage Temperature	Tstg	-40 to 150	°C	_



Recommended Operating Condition (Ta=25°C, unless otherwise noted)

Parameter	Terminal #	Ratings	Unit
Supply Voltage	12, 27	5.0	V
Function Supply Voltage Range	12, 27	4.75 to 5.25	V
Reference Frequency	11	3.579545 or 4.00	MHz
GND	10, 16	_	_

Electrical Characteristics

General

(Unless Otherwise Specified :

: Ta = 25°C, Vcc = 5.0V, Ref Signal = 3.579545MHz, Vi = 100mVpp, SW Condition = 1)

			Test	Test	Input	Input	SW		Limits	3	=	
No	Parameter	Symbol			Point	•	Condition	Min	Тур	Max	Unit	Note#
1	VIF/SIF Vcc Current	lcc1	1	Pin27	_	_		44	63	82	mA	
2	Logic Vcc Current	lcc2	1	Pin12	_	_		3.2	4.7	6.1	mA	
3	VIF/SIF Vcc Current @Defeat	lcc3	1	Pin12 Pin27	_	_	SW2=2	6.3	9.0	12.0	mA	
4	Video out Voltage @FM Mode	Vofm	1	TP24	_	_	SW25=2	-	0	0.5	V	
5	Ref. Signal Input Level	Fref	1	Pin11	Pin11	_		50	100	600	mVpp	

VIF Section 1

			Test	Test	Input	Input	SW		Limits	5	_	
No	Parameter	Symbol	Circuit		Point	Signal	Condition	Min	Тур	Max	Unit	Note#
6	Video out	Vodet	1	TP24	Pin17,18	SG1		0.95	1.20	1.45	Vpp	
7	Sync Tip level	Vsync	1	TP24	Pin17,18	SG2	A.	1.20	1.45	1.70	V	
8	Video S/N	VoS/N	1	TP24 A	Pin17,18	SG2	SW8=2 SW24=2	48	50	_	dB	1
9	Video out Freq. Response	BW	1	TP24	Pin17,18	SG3		6	7	_	MHz	2
10	Input sensitivity	VinMIN	1	TP24	Pin17,18	SG4		_	45	52	dBμV	3
11	Max.IF Input	VinMAX	1	TP24	Pin17,18	SG5		101	105	_	dΒμV	4
12	IF AGC Range	GR	1	_	-	_		49	60	_	dB	5
13	IF AGC voltage @80dBμV	IFAGC	1	TP21	Pin17,18	SG6		2.7	3.0	3.3	V	
14	Capture range U	CR-U	1	TP24	Pin17,18	SG7		0.80	1.00	_	MHz	6
15	Capture range L	CR-L	1	TP24	Pin17,18	SG7		1.38	1.75	_	MHz	7
16	Inter modulation	IM	1	TP24	Pin17,18	SG8		32	38	_	dB	8
17	D/G	DG	1	TP28	Pin17,18	SG9		_	3	5	%	
18	D/P	DP	1	TP28	Pin17,18	SG9		_	3	5	deg	
21	RF AGC High voltage	RFagcH	1	TP14	Pin17,18	SG10		4.4	4.7	5.0	V	
22	RF AGC Low voltage	RFagcL	1	TP14	Pin17,18	SG11		0	0.3	0.6	V	
23	RF AGC delay point @TV mode	RFDP1	1	TP14	Pin17,18	SG12		82	85	88	dBμV	9

VIF Section 2

		Test	Test	Input	Input	SW		Limits	5	_	
No Parameter	Symbol			•	Signal	_	Min	Тур	Max	Unit	Note#
24 AFT Sensitivity	μ	1	TP13	Pin17,18	SG15		10	26	40	mV /kHz	10
25 AFT High voltage	AFTH	1	TP13	Pin17,18	SG16		4.3	4.7	5	V	10
26 AFT Low voltage	AFTL	1	TP13	Pin17,18	SG17		0	0.3	0.7	V	10
27 AFT Mute voltage	AFTM	1	TP13	Pin17,18	SG18		2.4	2.5	2.6	V	
28 AFT Center voltage @US mode	VaftUS	1	TP13	Pin17,18	SG2		2.40	2.65	2.90	V	
29 AFT Center voltage @JP mode	VaftJP	1	TP13	Pin17,18	SG19	SW5=2	2.60	2.87	3.15	V	

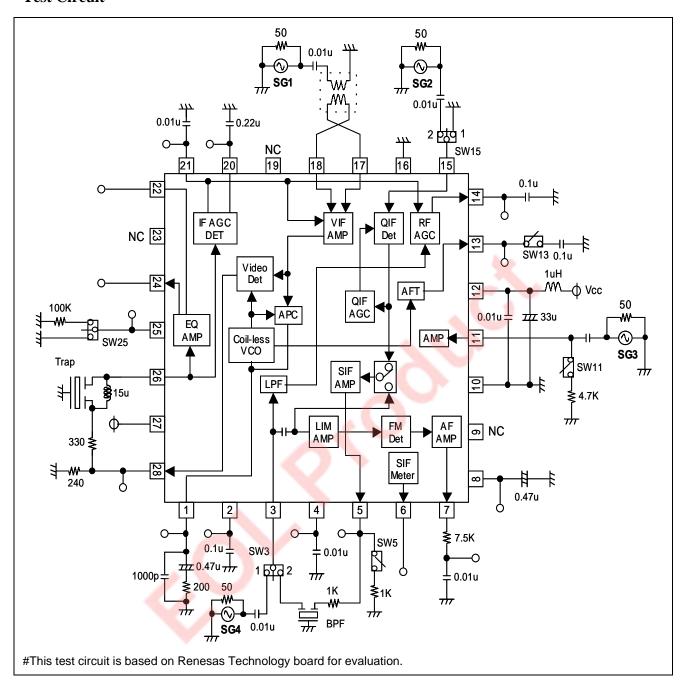
SIF Section

		Test	Test	Input	Input	SW -		Limits		-	
No Parameter	Symbol			Point	Signal	Condition I	Min	Тур	Max	Unit	Note#
30 AF output level @TV mode	VoAF1	1	TP7	Pin3	SG20	SW21=2	400	700	1000	mVrms	_
31 AF output THD @TV mode	THDAF1	1	TP7	Pin3	SG20	SW21=2 -		0.4	0.9	%	_
32 Audio S/N @TV mode	AF S/N1	1	TP7	Pin3	SG21	SW21=2	50	55	_	dB	11
33 Limiting sensitivity	LIM	1	TP7	Pin3	SG22 SG23	SW21=2 -	_	50	55	dBμV	12
34 QIF Output 1	QIF1	1	TP5	Pin17,18 Pin15	SG11 SG13	(94	100	106	dBμV	_
35 QIF Output 2	QIF2	1	TP5	Pin17,18 Pin15	SG11 SG14	(94	100	106	dBμV	

VCO Section

	Test	Test	Input	Input	sw	-	Limit	S	
No Parameter	Symbol Circ	uit Point	Point	Signal	Condition	Min	Тур	Max Unit	Note#
36 VIF VCO freerun	FvcofUS 1	TP13	_	_	SW8=2	-500	0	+500 kHz	13
@US mode					SW13&21=	2			
					SW25=3				
37 VIF VCO freerun	FvcofJP 1	TP13	_	_	SW5&8=2	-500	0	+500 kHz	13
@JP mode					SW13&21=	2			
					SW25=3				

Test Circuit



Input Signal

SG	50 Ω Termination					
1	f0=45.75MHz	Vi=90dBμV	fm=20kHz		AM=77.8%	
2	f0=45.75MHz	Vi=90dBμV	CW			
3	f1=45.75MHz	Vi=90dBμV	CW	1	Mixed signal	
	f2=Freq. Variable	Vi=70dBμV	CW	}		
4	f0=45.75MHz	Vi=Variable	fm=20kHz		AM=77.8%	
5	f0=45.75MHz	Vi=Variable	fm=20kHz		AM=16.0%	
6	f0=45.75MHz	Vi=80dBμV	CW			
7	f0=Freq. Variable	Vi=90dBμV	fm=20kHz		AM=77.8%	
8	f1=45.75MHz	Vi=90dBμV	CW			
	f2=42.17MHz	$Vi=80dB\mu V$	CW	}	Mixed signal	
	f3=41.25MHz	$Vi=80dB\mu V$	CW		X.	
9	f0=45.75MHz	Sync Tip Level = $90dB\mu V$				
	87.5% TV modulation 10	87.5% TV modulation 10 step waveform				
10	f0=45.75MHz	Vi=70dBμV	CW			
11	f0=45.75MHz	Vi=100dBμV	CW	D .		
12	f0=45.75MHz	Vi=Variable	CW	P		
13	f0=41.25MHz	Vi=100dBμV	CW			
14	f0=41.25MHz	Vi=70dBμV	CW			
15	f0=Freq. Variable	Vi=90dBμV	CW			
16	f0=45.75-0.5MHz	Vi=90dBμV	CW			
17	f0=45.75+0.5MHz	Vi=90dBμV	CW			
18	f0=45.75+/-5MHz	Vi=90dB _μ V	CW			
19	f0=58.75MHz	Vi=90dBμV	CW			
20	f0=4.5MHz	Vi=90dBμV	fm=1kHz +/-25kHz dev			
21	f0=4.5MHz	Vi=90dBμV	CW			
22	f0=4.5MHz	Vi=Variable	fm=1kHz +/-:	25kHz dev		
23	f0=4.5MHz	Vi=Variable	CW			

Mode Select

Mode Select		
		Recommended Condition : Ta = 25°C, Vcc = 5.0V
Inter / Split select	15pin condition	Recommendation
Split	QIF IN	QIF IN
Inter	within 0.5V	GND
TV / FM select	25pin condition	Recommendation
TV	DC Open	DC Open
Search(#1)	2.2V to 2.8V	1/2 Vcc
FM	within 1.0V	GND
#1 : Search mode use for sh	nipping test only.	
IF mute select	2pin condition	Recommendation
active	DC open	DC open
mute	within 0.5V	GND
US / JP select	5pin condition	Recommendation
US	no resistance	no resistance
JP	pull down 1.0kΩ +/–10%	1kΩ to GND
Ref Signal select	11pin condition	Recommendation
3.58M	no resistance	no resistance
4.00M	pull down 4.7kΩ +/–10%	4.7k Ω to GND
SIF mute select	8pin condition	Recommendation
active	DC open	DC open
mute	within 0.3V	GND
FM Mode IF Frequency (I	INTER)	
INTER	Ref Signal	IF Frequency
US	3.58MHz	42.341MHz
	4.00MHz	42.500MHz
JP	3.58MHz	55.330MHz
	4.00MHz	55.357MHz
FM Mode IF Frequency (S	SPLIT)	
SPLIT	Ref Signal	IF Frequency
US	3.58MHz	41.250MHz
	4.00MHz	41.250MHz
JP	3.58MHz	54.250MHz
	4.00MHz	54.250MHz
	1.0011112	0 1.200Wii 12

RENESAS

NOTE

Note1 Video S/N: VoS/N

Input SG2 to VIF IN (Pin17, 18) and measure the video out (TP24A) noise in r.m.s. through a 5MHz (-3dB) L.P.F.

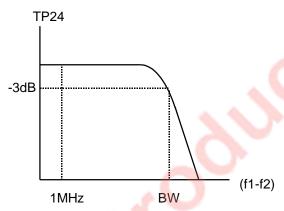
$$S/N = 20log \left(\frac{0.7 \times Vodet \quad (Vpp)}{NOISE \quad (rms)} \right)$$
 (dB)

Note2 Video Band Width: BW

1. Measure the 1MHz component level of Video output (TP24) with a spectrum analyzer when SG3 (f2 = 44.75MHz) is input to VIF IN (Pin17, 18).

At that time, measure the voltage at TP21, and then fix TP21 at that voltage.

2. Reduce f2 and measure the value of (f1-f2) when the (f1-f2) component level reaches -3dB from the 1MHz component level as shown below.



Note3 Input Sensitivity: VinMIN

Input SG4 ($Vi = 90dB\mu$) to VIF IN(Pin17, 18), and then gradually reduce Vi and measure the input level when the 20kHz component of Video output (TP24) reaches -3dB from Vo det level.

Note4 Maximum Allowable Input: VinMAX

- 1. Input SG5 (Vi = $90dB\mu$) to VIF IN (Pin17, 18), and measure the level of the 20kHz component of Video output (TP24).
- 2. Gradually increase the Vi of SG5 and measure the input level when the output reaches –3dB.

Note5 AGC Control Range : GR

$$GR = VinMAX - VinMIN$$
 (dB)

Note6 Capture range: CR-U

- 1. Increase the frequency of SG7 until the VCO is out of locked-oscillation.
- 2. And decrease the frequency of SG7 and measure the frequency fU when the VCO is locked.

$$CR-U = fU - 45.75$$
 (MHz)

Note7 Capture range: CR-L

- 1. Decrease the frequency of SG7 until the VCO is out of locked-oscillation.
- 2. And increase the frequency of SG7 and measure the frequency fL when the VCO is locked.

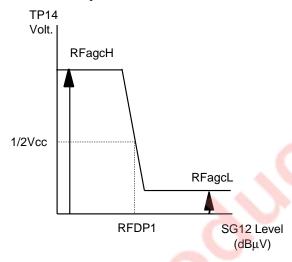
$$CR-L = 45.75 - fL$$
 (MHz)

Note8 Inter modulation: IM

- 1. Input SG8 to VIF IN(Pin17,18), and measure video output (TP24) with an oscilloscope.
- 2. Adjust AGC filter voltage TP21 so that the minimum DC level of the output waveform is Vsync.
- 3. At that time, measure TP24 with a spectrum analyzer. The inter modulation is defined as a difference between 0.92MHz and 3.58 MHz frequency components.

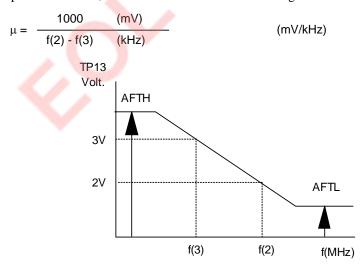
Note9 RF AGC Delay Point (TV Mode): RFDP1

- 1. Input SG12 to VIF IN (Pin17, 18) and gradually reduce level and then measure the input level when RF AGC output (TP14) reaches 1/2Vcc, as shown below.
- 2. At that time, the state of Pin3 is DC open.



Note10 AFT sensitivity: μ, Maximum AFT voltage:AFTH, Minimum AFT voltage:AFTL

- 1. Input SG15 to VIF IN (Pin17,18), and set the frequency of SG15 so that the voltage of AFT output (TP13) is 3 volt. This frequency is named f(3).
- 2. Set the frequency of SG15 so that the AFT output voltage is 2 volt. This frequency is named f(2).
- 3. IN the graph shown below, maximum and minimum DC voltage are AFTH and AFTL, respectively.



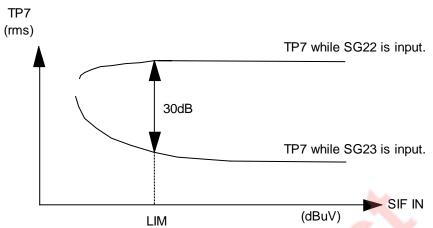
Note11 Audio S/N(TV Mode): AF S/N1

Input SG21 to SIF IN (Pin3), and measure the output noise level of Audio output (TP7) with FLAT-r.m.s. This level is named AFN1.

AF S/N1 = 20log
$$\left(\begin{array}{cc} VoAF1 & (mVrms) \\ \hline AFN1 & (mVrms) \end{array}\right)$$
 (dB)

Note12 Limiting Sensitivity: LIM

- 1. Input SG22 to LIM IN (Pin3), and measure the 1kHz component level of AF output (TP7) with FLAT-r.m.s.
- 2. Input SG23 to LIM IN (Pin3), and measure the noise level of AF output (TP7) with FLAT-r.m.s.
- 3. The input limiting sensitivity is defined as the input level when the difference between each 1kHz components of audio output (TP7) is 30dB, as shown below.



Note13 VIF VCO Freerun frequency: FvcofUS / FvcofJP

Input 3.579545MHz to Ref IN (Pin11), and set up SW as shown following.

	US Mode		JP Mode		<u></u>
SW No.	Setting	Condition	Setting	Condition	
5	1	No-Connecting R	2	Connecting $1k\Omega$	*VCO SW : US/JP
8	2	GND	2	GND	
11	1	No-Connecting R	1	No-Connecting R	
13	2	No-Connecting C	2	No-Connecting C	
21	2	GND	2	GND	
25	3	Add to 2.5 Volt.	3	Add to 2.5 Volt.	

- 1. Measure the frequency of output signal at AFT out (TP13) each when be selected US or JP by SW5.
- 2. Measured frequency's are defined FaftUS (US Mode), FaftJP(JP Mode).

The VCO freerun frequency is calculated by following.

$$<$$
Fref = 3.579545MHz $>$

US Mode

$$FvcofUS = 52.915(MHz) - 2xFaftUS(MHz) - 45.75(MHz)$$
[MHz]

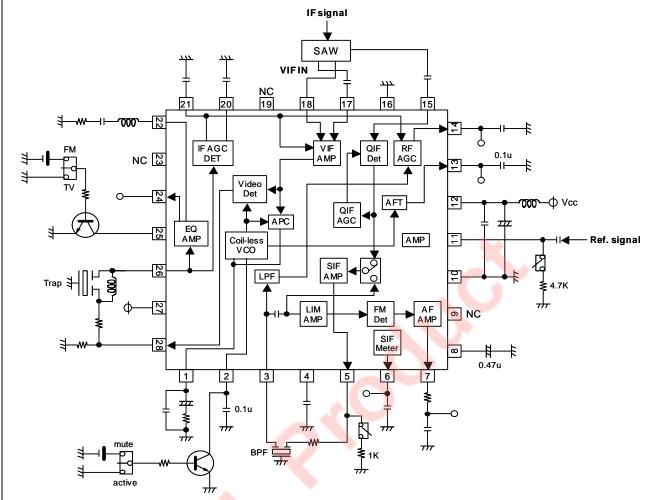
JP Mode

$$FvcofJP = 65.925(MHz) - 2xFaftJP(MHz) - 58.75(MHz)$$
 [MHz]

Case of Fref frequency is 4.00MHz, SW11 should be set up 2 (Pin11 is connected $4.7k\Omega$ to GND).

Others condition's are same as case of 3.58MHz mode, and the VCO freerun frequency is calculated by following.

Application



Recommendation

- * By pass capacitance for Logic Vcc (Pin12) should be mounted close hard by Logic GND (Pin10)
- * In order to mitigate the surroundings lump by the VIF input, the balanced connection from a SAW filter to the VIF input pin of 17,18 recommends a putter which serves as a 1t coil by Tip C or the jumper.

Special components

SAW: SAF45MA210Z TRP: TPSRA4M50B00 BPF: SFSH4.5MEB2

T	1	ъ.	•
Paci	kage	Dim	ensions

28PJW

Note: Please contact Renesas Technology Corporation for further details.



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Renesas Technology (Shanghai) Co., Ltd. 26/F., Ruijin Building, No.205 Maoming Road (S), Shanghai 200020, China Tel: <86> (21) 6472-1001, Fax: <86> (21) 6415-2952

Renesas Technology Singapore Pte. Ltd.
1, Harbour Front Avenue, #06-10, Keppel Bay Tower, Singapore 098632 Tel: <65> 6213-0200, Fax: <65> 6278-8001